

ZENER DIODES

PRODUCT SUMMARY

V_Z range: 2.4 to 75 Volts
 Power dissipation: 500mW

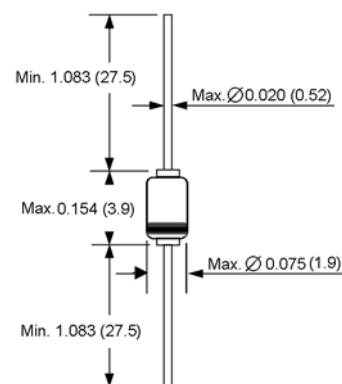


FEATURES

The Zener voltages are graded according to the international E 24 standard. Higher Zener voltages and 1% tolerance available on request.

Diodes available in these tolerance series:
 $\pm 2\%$ BZX79-B, $\pm 3\%$ BZX79-F, $\pm 5\%$ BZX79-C.

DO-204AH (DO-35 Glass)



Dimensions in inches and (millimeters)

MECHANICAL DATA

Case: DO-35 Glass Case
 Weight: approx. 0.13g



MAXIMUM RATINGS AND THERMAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Zener current see table "Characteristics"			
Power dissipation at $T_{amb} = 25^\circ\text{C}$	P_{tot}	500 ⁽¹⁾	mW
Junction temperature	T_J	-65 to +175	$^\circ\text{C}$
Storage temperature range	T_S	-65 to +175	$^\circ\text{C}$
Continuous forward current	I_F	250	mA
Thermal resistance junction to ambient air	$R_{\theta JA}$	0.3 ⁽¹⁾	$^\circ\text{C/mW}$
Peak reverse power dissipation (non-repetitive) $t_p = 100\mu\text{s}$ square wave	P_{ZSM}	40	W

Notes: 1. Valid provided that leads are kept at ambient temperature at a distance of 8mm from case.

ELECTRICAL CHARACTERISTICS

($T_A=25^{\circ}\text{C}$ unless otherwise noted) Maximum $V_F=0.9\text{V}$ at $I_F=10\text{mA}$

Type number y=B for $\pm 2\% V_Z$ y=F for $\pm 3\% V_Z$ y=C for $\pm 5\% V_Z$	Dynamic resistance		Temp. coefficient of zener voltage at $I_Z=5\text{mA}$ $\mu\text{mV}/^{\circ}\text{C}$		Reverse leakage current		Admissible zener current ⁽²⁾	Capacitance $V_F=0$ $f=1\text{MHz}$ (pF) Max.	Non-Repetitive peak reverse current at $t_p=100\mu\text{s}$ I_{ZSM} (A)
	at $I_Z=5\text{mA}$ $f=1\text{kHz}$ r_{Z1} (Ω) Max.	at $I_Z=1\text{mA}$ $f=1\text{kHz}$ r_{Z1} (Ω) Max.	Min.	Max.	I_R (nA)	at V_R (Volts)			
BZX79 - y2V4	100	< 600	- 0.08	- 0.06	50,000	1	167	450	6.0
BZX79 - y2V7	100	< 600	- 0.08	- 0.06	20,000	1	135	450	6.0
BZX79 - y3V0	95	< 600	- 0.08	- 0.06	10,000	1	125	450	6.0
BZX79 - y3V3	95	< 600	- 0.08	- 0.05	5,000	1	115	450	6.0
BZX79 - y3V6	90	< 600	- 0.08	- 0.04	5,000	1	105	450	6.0
BZX79 - y3V9	90	< 600	- 0.07	- 0.03	3,000	1	95	450	6.0
BZX79 - y4V3	90	< 600	- 0.04	- 0.01	3,000	1	90	450	6.0
BZX79 - y4V7	80	500	- 0.03	+ 0.01	3,000	1	85	300	6.0
BZX79 - y5V1	60	480	- 0.02	+ 0.05	2,000	1	80	300	6.0
BZX79 - y5V6	40	400	- 0.01	+ 0.06	1,000	1	70	300	6.0
BZX79 - y6V2	10	150	0	+ 0.07	3,000	2	64	200	6.0
BZX79 - y6V8	15	80	+ 0.01	+ 0.08	2,000	3	58	200	6.0
BZX79 - y7V5	15	80	+ 0.01	+ 0.09	1,000	5	53	150	4.0
BZX79 - y8V2	15	80	+ 0.01	+ 0.09	700	6	47	150	4.0
BZX79 - y9V1	15	100	+ 0.02	+ 0.10	500	7	43	150	3.0
BZX79 - y10	20	150	+ 0.03	+ 0.11	200	7.5	40	90	3.0
BZX79 - y11	20	150	+ 0.03	+ 0.11	100	8.5	36	85	2.5
BZX79 - y12	25	150	+ 0.03	+ 0.11	100	9	32	85	2.5
BZX79 - y13	30	170	+ 0.03	+ 0.11	100	10	29	80	2.5
BZX79 - y15	30	200	+ 0.03	+ 0.11	50	11	27	75	2.0
BZX79 - y16	40	200	+ 0.03	+ 0.11	50	12	24	75	1.5
BZX79 - y18	45	225	+ 0.03	+ 0.11	50	14	21	70	1.5
BZX79 - y20	55	225	+ 0.03	+ 0.11	50	15	20	60	1.5
BZX79 - y22	55	250	+ 0.03	+ 0.11	50	17	18	60	1.3
BZX79 - y24	70	250	+ 0.04	+ 0.12	50	18	16	55	1.3
BZX79 - y27	80 ⁽³⁾	300 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	20	14	50	1.0
BZX79 - y30	80 ⁽³⁾	300 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	22	13	50	1.0
BZX79 - y33	80 ⁽³⁾	325 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	24	12	45	0.9
BZX79 - y36	90 ⁽³⁾	350 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	27	11	45	0.8
BZX79 - y39	130 ⁽³⁾	350 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	28	10	45	0.7
BZX79 - y43	150 ⁽³⁾	375 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	32	9.2	40	0.6
BZX79 - y47	170 ⁽³⁾	375 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	35	8.5	40	0.5
BZX79 - y51	180 ⁽³⁾	400 ⁽⁴⁾	+ 0.04 ⁽³⁾	+ 0.12	50	38	7.8	40	0.4
BZX79 - y56	200 ⁽³⁾	425 ⁽⁴⁾	typ. +0.1 ⁽³⁾		50	39	7.1	40	0.3
BZX79 - y62	215 ⁽³⁾	450 ⁽⁴⁾	typ. +0.1 ⁽³⁾		50	43	6.4	35	0.3
BZX79 - y68	240 ⁽³⁾	475 ⁽⁴⁾	typ. +0.1 ⁽³⁾		50	48	5.8	35	0.3
BZX79 - y75	255 ⁽³⁾	500 ⁽⁴⁾	typ. +0.1 ⁽³⁾		50	53	5.3	35	0.2

- Notes:
1. Tested with pulses $t_p=5\text{ms}$.
 2. Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case.
 3. at $I_Z=2.0\text{mA}$
 4. at $I_Z=0.5\text{mA}$
- y = Zener voltage tolerance designator

ELECTRICAL CHARACTERISTICS

(T_A=25°C unless otherwise noted) Maximum V_F=0.9V at I_F=10mA

Type number ±5% Tol.	Zener voltage range ⁽¹⁾ at I _Z =5mA V _Z (Volts)	
	Min.	Max.
BZX79-C2V4	2.20	2.60
BZX79-C2V7	2.50	2.90
BZX79-C3V0	2.80	3.20
BZX79-C3V3	3.10	3.50
BZX79-C3V6	3.40	3.80
BZX79-C3V9	3.70	4.10
BZX79-C4V3	4.00	4.60
BZX79-C4V7	4.40	5.00
BZX79-C5V1	4.80	5.40
BZX79-C5V6	5.20	6.00
BZX79-C6V2	5.80	6.60
BZX79-C6V8	6.40	7.20
BZX79-C7V5	7.00	7.90
BZX79-C8V2	7.70	8.70
BZX79-C9V1	8.50	9.60
BZX79-C10	9.40	10.60
BZX79-C11	10.40	11.60
BZX79-C12	11.40	12.70
BZX79-C13	12.40	14.10
BZX79-C15	13.80	15.60
BZX79-C16	15.30	17.10
BZX79-C18	16.80	19.10
BZX79-C20	18.80	21.20
BZX79-C22	20.80	23.30
BZX79-C24	22.80	25.60
BZX79-C27	25.10	28.90 ⁽³⁾
BZX79-C30	28.00	32.00 ⁽³⁾
BZX79-C33	31.00	35.00 ⁽³⁾
BZX79-C36	34.00	38.00 ⁽³⁾
BZX79-C39	37.00	41.00 ⁽³⁾
BZX79-C43	40.00	46.00 ⁽³⁾
BZX79-C47	44.00	50.00 ⁽³⁾
BZX79-C51	48.00	54.00 ⁽³⁾
BZX79-C56	52.00	60.00 ⁽³⁾
BZX79-C62	58.00	66.00 ⁽³⁾
BZX79-C68	64.00	72.00 ⁽³⁾
BZX79-C75	70.00	79.00 ⁽³⁾

Type number ±3% Tol.	Zener voltage range ⁽¹⁾ at I _Z =5mA V _Z (Volts)	
	Min.	Max.
BZX79-F2V4	2.33	2.47
BZX79-F2V7	2.62	2.78
BZX79-F3V0	2.91	3.09
BZX79-F3V3	3.20	3.40
BZX79-F3V6	3.49	3.71
BZX79-F3V9	3.78	4.02
BZX79-F4V3	4.17	4.43
BZX79-F4V7	4.56	4.84
BZX79-F5V1	4.95	5.25
BZX79-F5V6	5.43	5.77
BZX79-F6V2	6.01	6.39
BZX79-F6V8	6.60	7.00
BZX79-F7V5	7.28	7.72
BZX79-F8V2	7.95	8.45
BZX79-F9V1	8.83	9.37
BZX79-F10	9.70	10.30
BZX79-F11	10.67	11.33
BZX79-F12	11.64	12.36
BZX79-F13	12.61	13.39
BZX79-F15	14.55	15.45
BZX79-F16	15.50	16.50
BZX79-F18	17.50	18.50
BZX79-F20	19.40	20.60
BZX79-F22	21.30	22.70
BZX79-F24	23.30	24.70
BZX79-F27	26.20	27.80 ⁽³⁾
BZX79-F30	29.10	30.90 ⁽³⁾
BZX79-F33	32.00	34.00 ⁽³⁾
BZX79-F36	34.90	37.10 ⁽³⁾
BZX79-F39	37.80	40.20 ⁽³⁾
BZX79-F43	41.70	44.30 ⁽³⁾
BZX79-F47	45.60	48.40 ⁽³⁾
BZX79-F51	49.50	52.50 ⁽³⁾
BZX79-F56	54.30	57.70 ⁽³⁾
BZX79-F62	60.10	63.90 ⁽³⁾
BZX79-F68	66.00	70.00 ⁽³⁾
BZX79-F75	72.80	77.20 ⁽³⁾

Type number ±2% Tol.	Zener voltage range ⁽¹⁾ at I _Z =5mA V _Z (Volts)	
	Min.	Max.
BZX79-B2V4	2.35	2.45
BZX79-B2V7	2.65	2.75
BZX79-B3V0	2.94	3.06
BZX79-B3V3	3.23	3.37
BZX79-B3V6	3.53	3.67
BZX79-B3V9	3.82	3.98
BZX79-B4V3	4.21	4.39
BZX79-B4V7	4.61	4.79
BZX79-B5V1	5.00	5.20
BZX79-B5V6	5.49	5.71
BZX79-B6V2	6.08	6.32
BZX79-B6V8	6.66	6.94
BZX79-B7V5	7.35	7.65
BZX79-B8V2	8.04	8.36
BZX79-B9V1	8.92	9.28
BZX79-B10	9.80	10.20
BZX79-B11	10.80	11.20
BZX79-B12	11.80	12.20
BZX79-B13	12.70	13.30
BZX79-B15	14.70	15.30
BZX79-B16	15.70	16.30
BZX79-B18	17.60	18.40
BZX79-B20	19.60	20.40
BZX79-B22	21.60	22.40
BZX79-B24	23.50	24.50
BZX79-B27	26.50	27.50 ⁽³⁾
BZX79-B30	29.40	30.60 ⁽³⁾
BZX79-B33	32.30	33.70 ⁽³⁾
BZX79-B36	35.30	36.70 ⁽³⁾
BZX79-B39	38.20	39.80 ⁽³⁾
BZX79-B43	42.10	43.90 ⁽³⁾
BZX79-B47	46.10	47.90 ⁽³⁾
BZX79-B51	50.00	52.00 ⁽³⁾
BZX79-B56	54.90	57.10 ⁽³⁾
BZX79-B62	60.80	63.20 ⁽³⁾
BZX79-B68	66.60	69.40 ⁽³⁾
BZX79-B75	73.50	76.50 ⁽³⁾

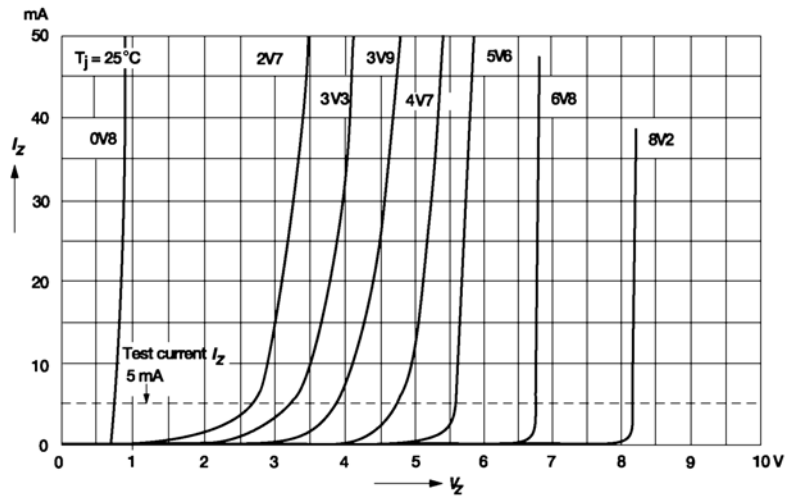
Notes: 1. Tested with pulses t_p=5ms
2. Valid provided that electrodes are kept at ambient temperature
3. at I_Z=2.0 mA
See BZX79-y table for all characteristics other than zener voltage range.

RATINGS AND CHARACTERISTIC CURVES

($T_A=25^{\circ}\text{C}$ unless otherwise noted)

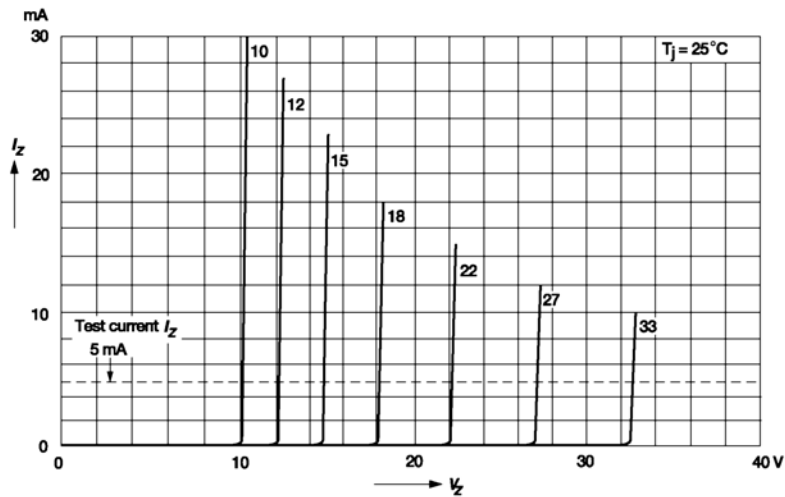
Breakdown characteristics

at $T_J = \text{constant (pulsed)}$



Breakdown characteristics

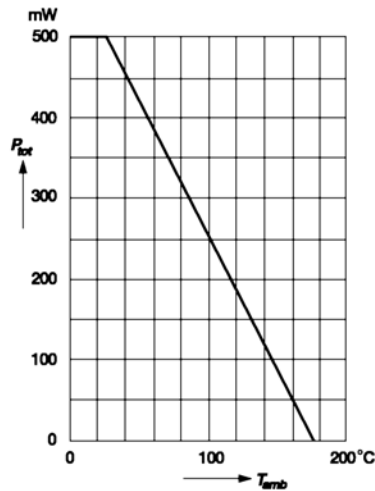
at $T_J = \text{constant (pulsed)}$



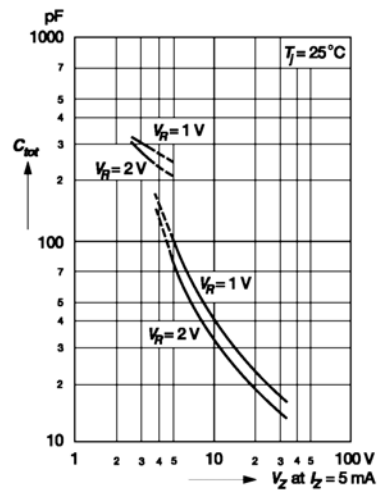
RATINGS AND CHARACTERISTIC CURVES

($T_A=25^{\circ}\text{C}$ unless otherwise noted)

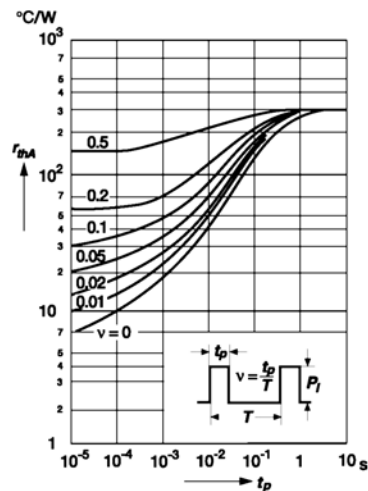
Admissible power dissipation versus ambient temperature
Valid provided that leads are kept ambient temperature at a distance of 8 mm from case.



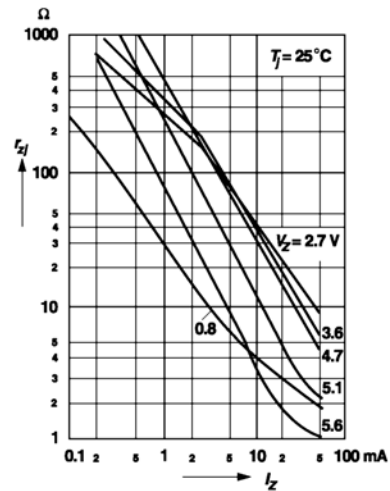
Capacitance versus Zener voltage



Pulse thermal resistance versus pulse duration
Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case.



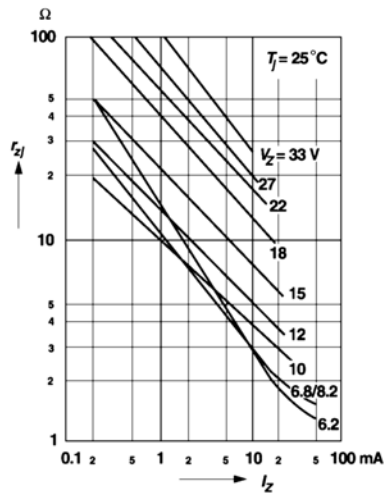
Dynamic resistance versus Zener current



RATINGS AND CHARACTERISTIC CURVES

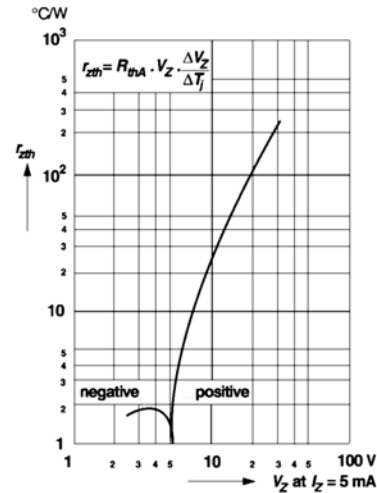
($T_A = 25^\circ\text{C}$ unless otherwise noted)

Dynamic resistance
versus Zener current

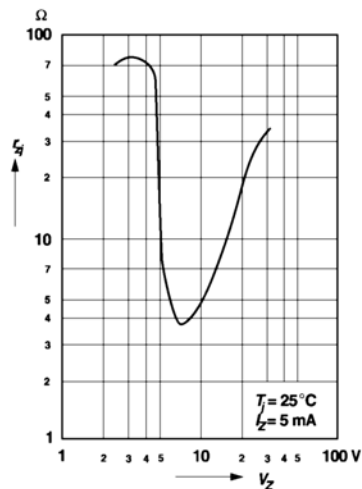


Thermal differential resistance
versus Zener voltage

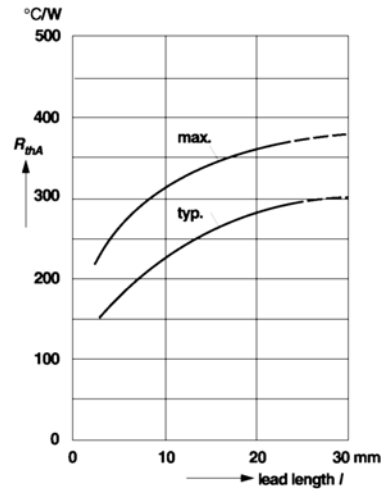
Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case.



Dynamic resistance
versus Zener voltage



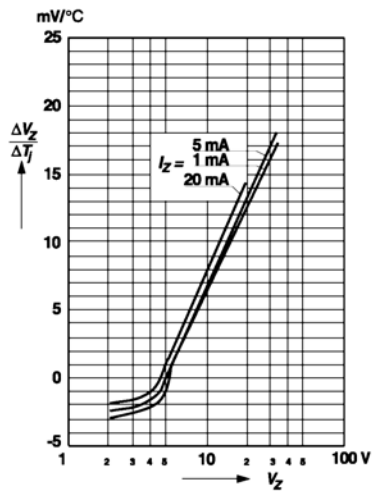
Thermal resistance
versus lead length



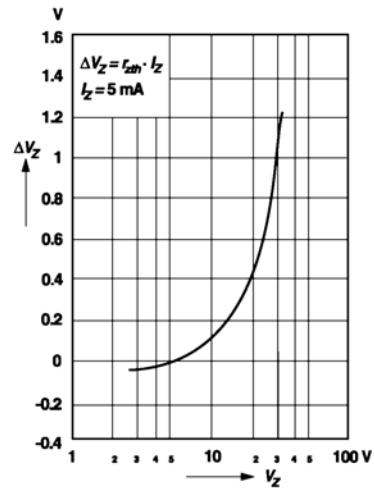
RATINGS AND CHARACTERISTIC CURVES

($T_A=25^{\circ}\text{C}$ unless otherwise noted)

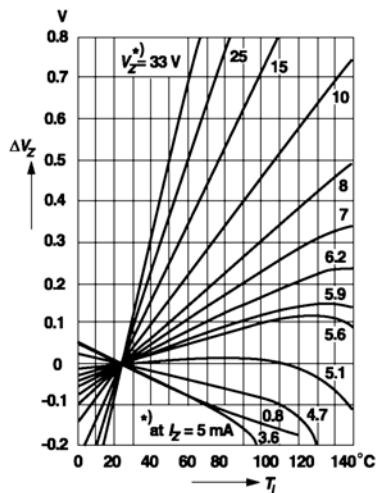
Temperature dependence of Zener voltage
versus Zener voltage



Change of Zener voltage from turn-on
up to the point of thermal equilibrium
versus Zener voltage



Change of Zener voltage
versus junction temperature



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